

# BLF574XR; BLF574XRS

Power LDMOS transistor

Rev. 1 — 20 June 2013

Product data sheet

## 1. Product profile

### 1.1 General description

A 600 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 500 MHz band. This product is an enhanced version of the BLF574 using NXP's XR process to provide maximum ruggedness capability in the most severe applications without compromising the RF performance.

Table 1. Application information

Test signal	f (MHz)	V <sub>DS</sub> (V)	P <sub>L</sub> (W)	G <sub>p</sub> (dB)	η <sub>D</sub> (%)
CW	225	50	600	23.5	74.5
pulsed RF	225	50	600	24	74.7

### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 500 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

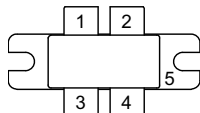
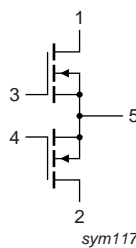
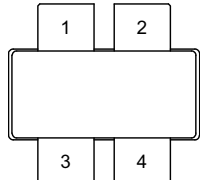
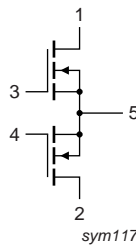
### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications



## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
<b>BLF574XR (SOT1214A)</b>			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		
<b>BLF574XRS (SOT1214B)</b>			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF574XR	-	flanged ceramic package; 2 mounting holes; 4 leads	SOT1214A
BLF574XRS	-	earless flanged ceramic package; 4 leads	SOT1214B

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	110	V
$V_{GS}$	gate-source voltage		-6	+11	V
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the on-line MTF calculator.

## 5. Thermal characteristics

**Table 5. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_j = 150\text{ °C}$	[1][2] 0.18	K/W

[1]  $T_j$  is the junction temperature.

[2]  $R_{th(j-c)}$  is measured under RF conditions.

## 6. Characteristics

**Table 6. DC characteristics**

$T_j = 25\text{ °C}$ ; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}$ ; $I_D = 2.75\text{ mA}$	110	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}$ ; $I_D = 275\text{ mA}$	1.25	1.7	2.25	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0\text{ V}$ ; $V_{DS} = 50\text{ V}$	-	-	1.4	$\mu\text{A}$
$I_{DSX}$	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$ ; $V_{DS} = 10\text{ V}$	-	38	-	A
$I_{GSS}$	gate leakage current	$V_{GS} = 11\text{ V}$ ; $V_{DS} = 0\text{ V}$	-	-	140	nA
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$ ; $I_D = 9.625\text{ A}$	-	0.15	-	$\Omega$

**Table 7. DC characteristics**

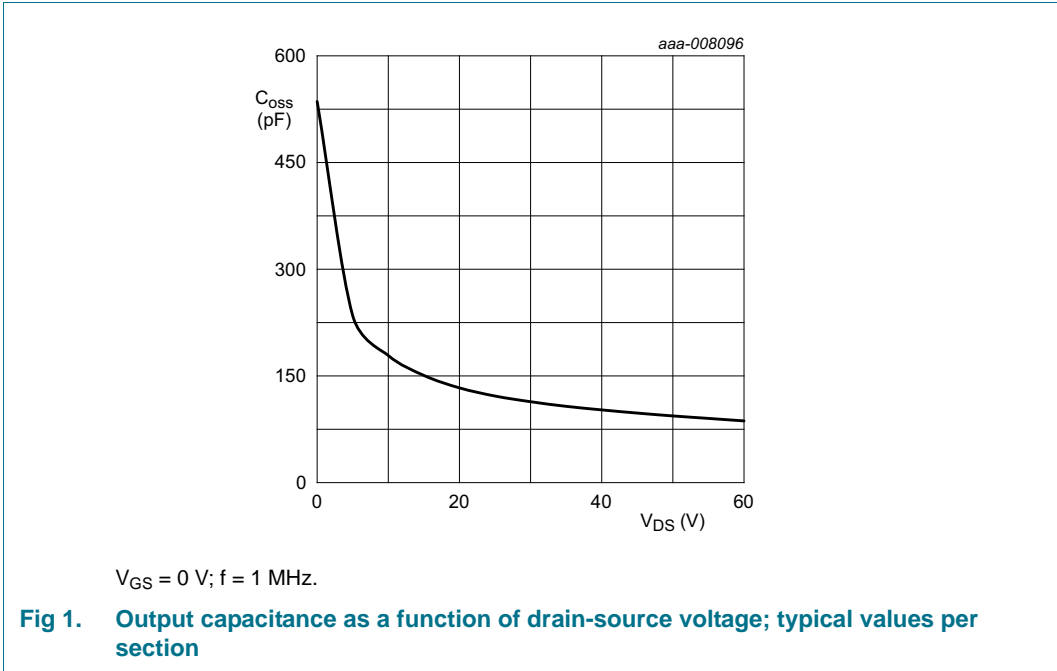
$T_j = 25\text{ °C}$ ; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$C_{rs}$	feedback capacitance	$V_{GS} = 0\text{ V}$ ; $V_{DS} = 50\text{ V}$ ; $f = 1\text{ MHz}$	-	2.4	-	pF
$C_{iss}$	input capacitance	$V_{GS} = 0\text{ V}$ ; $V_{DS} = 50\text{ V}$ ; $f = 1\text{ MHz}$	-	210	-	pF
$C_{oss}$	output capacitance	$V_{GS} = 0\text{ V}$ ; $V_{DS} = 50\text{ V}$ ; $f = 1\text{ MHz}$	-	94	-	pF

**Table 8. RF characteristics**

Test signal: CW;  $f = 225\text{ MHz}$ ; RF performance at  $V_{DS} = 50\text{ V}$ ;  $I_{DQ} = 100\text{ mA}$ ;  $T_{case} = 25\text{ °C}$ ; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$P_L = 600\text{ W}$	21.65	23.5	-	dB
$RL_{in}$	input return loss	$P_L = 600\text{ W}$	-	-17	-13	dB
$\eta_D$	drain efficiency	$P_L = 600\text{ W}$	70	74.5	-	%

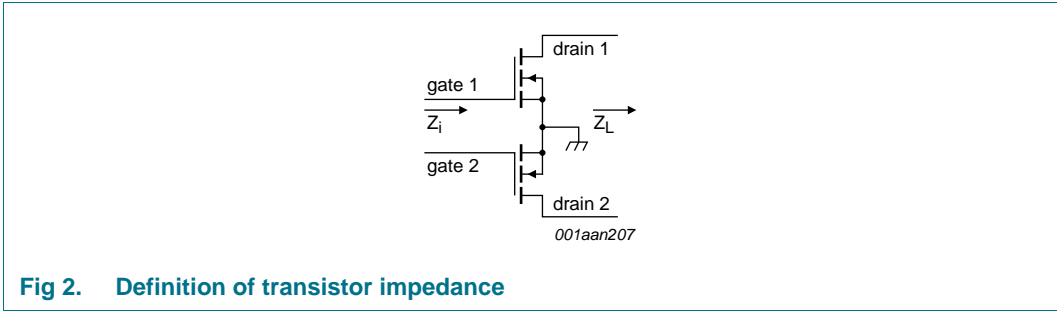


7. Test information

7.1 Ruggedness in class-AB operation

The BLF574XR and BLF574XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions:  $V_{DS} = 50\text{ V}$ ;  $I_{Dq} = 100\text{ mA}$ ;  $P_L = 600\text{ W}$  pulsed;  $f = 225\text{ MHz}$ .

7.2 Impedance information

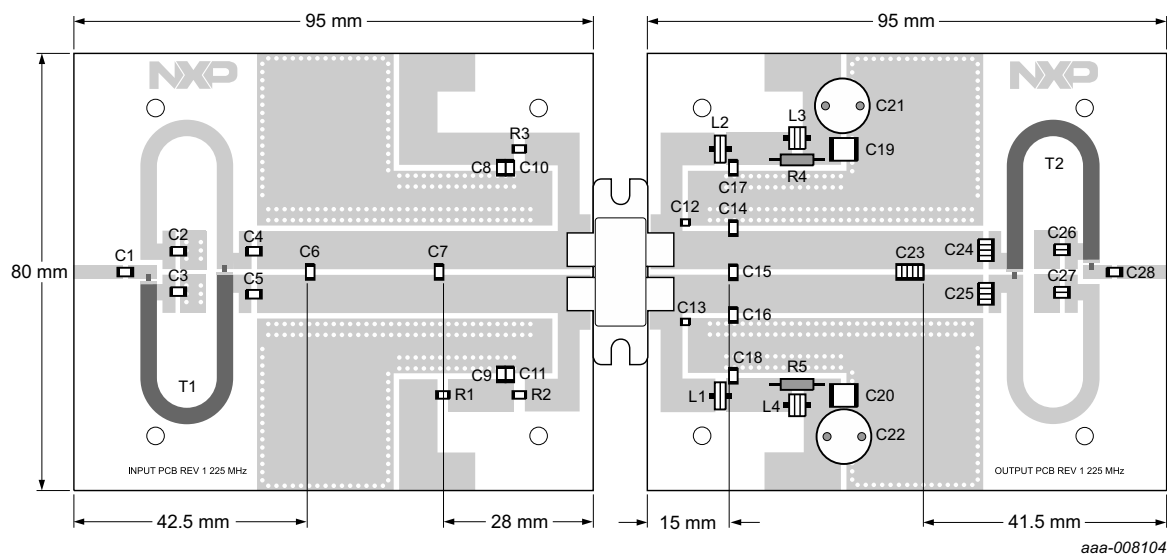


**Table 9. Typical push-pull impedance**

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS} = 50\text{ V}$  and  $P_L = 600\text{ W}$ .

f (MHz)	$Z_i$ ( $\Omega$ )	$Z_L$ ( $\Omega$ )
225	$4.67 - j5.47$	$5.66 + j2.05$

### 7.3 Test circuit



Printed-Circuit Board (PCB) Rogers 5880:  $\epsilon_r = 2.2$  F/m; thickness = 0.79 mm; thickness copper plating = 35  $\mu\text{m}$ .

See [Table 10](#) for a list of components.

**Fig 3. Component layout for class-AB production test circuit**

### Table 10. List of components

For test circuit see [Figure 3](#).

Component	Description	Value	Remarks
C1, C2, C3, C10, C11, C17, C18	multilayer ceramic chip capacitor	1 nF	[1]
C4, C5	multilayer ceramic chip capacitor	62 pF	[1]
C6, C7	multilayer ceramic chip capacitor	51 pF	[1]
C8, C9	multilayer ceramic chip capacitor	4.7 $\mu$ F, 50 V	Kemet C1210X475K5RAC-T4
C12, C13	multilayer ceramic chip capacitor	33 pF	[2]
C14, C16	multilayer ceramic chip capacitor	43 pF	[1]
C15	multilayer ceramic chip capacitor	20 pF	[1]
C19, C20	multilayer ceramic chip capacitor	4.7 $\mu$ F; 100 V	
C21, C22	electrolytic capacitor	470 $\mu$ F; 63 V	
C23	multilayer ceramic chip capacitor	5 $\times$ 12 pF	[3]
C24, C25	multilayer ceramic chip capacitor	4 $\times$ 16 pF	[3]
C26, C27	multilayer ceramic chip capacitor	2 $\times$ 510 pF	[3]
C28	multilayer ceramic chip capacitor	56 pF	[1]
L1, L2	2 turn 1 mm copper wire	D = 3 mm, length = 3 mm	
L3, L4	3 turn 1 mm copper wire	D = 3 mm, length = 3 mm	
R1	chip resistor	0 $\Omega$	

Table 10. List of components ...continued  
For test circuit see [Figure 3](#).

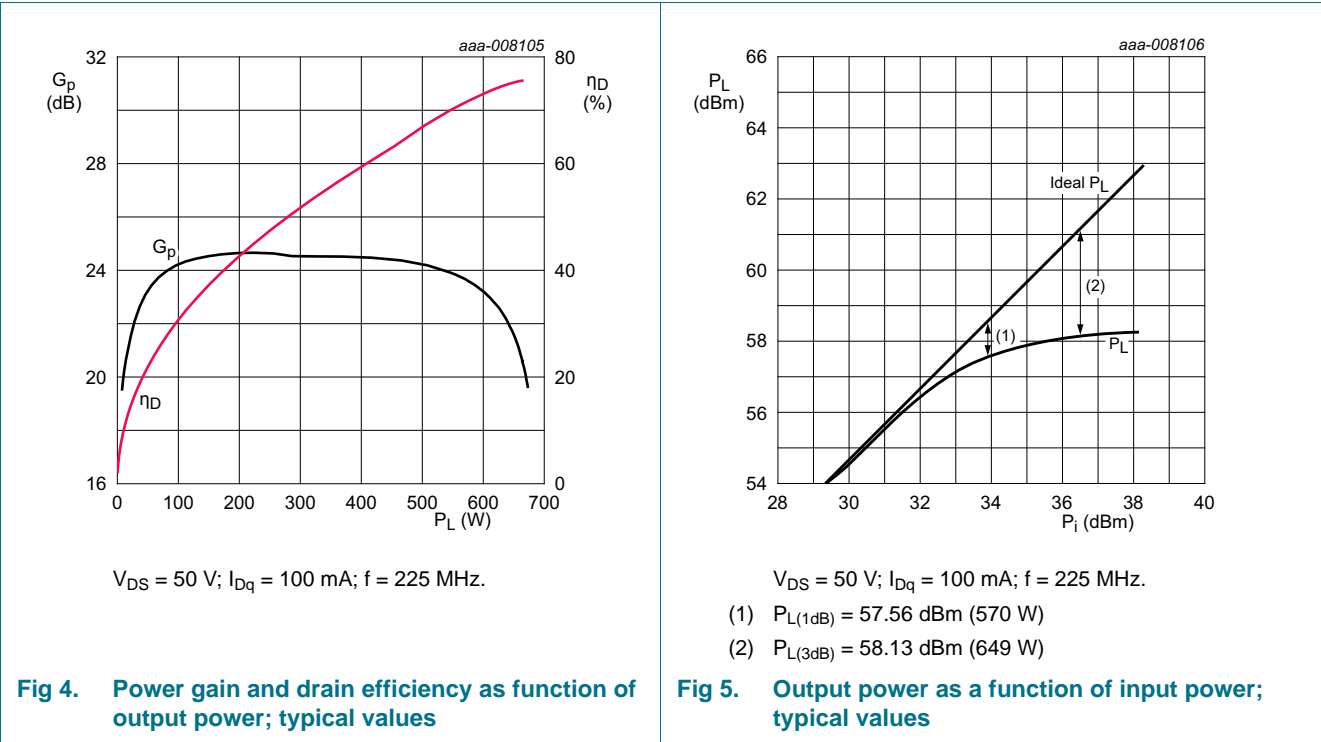
Component	Description	Value	Remarks
R2, R3	chip resistor	10 Ω	SMD 1206
R4, R5	metal film resistor	2 Ω, 0.6 W	
T1, T2	semi rigid coax	50 Ω, 58 mm	HUBER+SUHNER EZ-141-AL-TP-M17

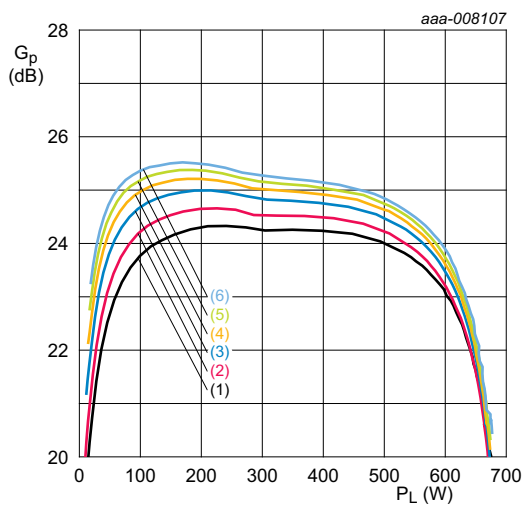
- [1] American Technical Ceramics type 100B or capacitor of same quality.  
[2] American Technical Ceramics type 100A or capacitor of same quality.  
[3] American Technical Ceramics type 800B or capacitor of same quality.

7.4 Graphical data

The following figures are measured in a class-AB production test circuit.

7.4.1 1-Tone CW

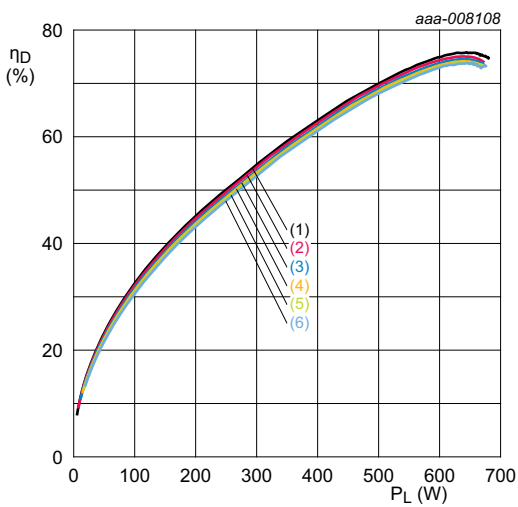




$V_{DS} = 50\text{ V}$ ;  $f = 225\text{ MHz}$ .

- (1)  $I_{Dq} = 50\text{ mA}$
- (2)  $I_{Dq} = 100\text{ mA}$
- (3)  $I_{Dq} = 200\text{ mA}$
- (4)  $I_{Dq} = 300\text{ mA}$
- (5)  $I_{Dq} = 400\text{ mA}$
- (6)  $I_{Dq} = 500\text{ mA}$

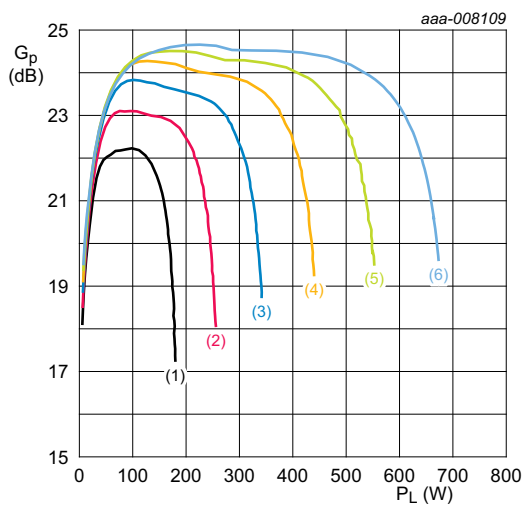
Fig 6. Power gain as a function of output power; typical values



$V_{DS} = 50\text{ V}$ ;  $f = 225\text{ MHz}$ .

- (1)  $I_{Dq} = 50\text{ mA}$
- (2)  $I_{Dq} = 100\text{ mA}$
- (3)  $I_{Dq} = 200\text{ mA}$
- (4)  $I_{Dq} = 300\text{ mA}$
- (5)  $I_{Dq} = 400\text{ mA}$
- (6)  $I_{Dq} = 500\text{ mA}$

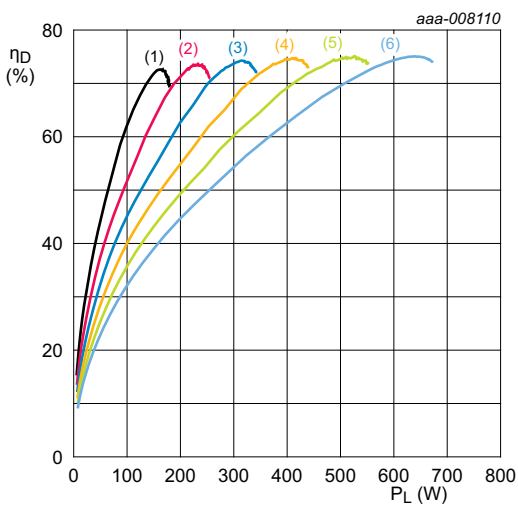
Fig 7. Drain efficiency as a function of output power; typical values



$I_{DQ} = 100\text{ mA}$ ;  $f = 225\text{ MHz}$ .

- (1)  $V_{DS} = 25\text{ V}$
- (2)  $V_{DS} = 30\text{ V}$
- (3)  $V_{DS} = 35\text{ V}$
- (4)  $V_{DS} = 40\text{ V}$
- (5)  $V_{DS} = 45\text{ V}$
- (6)  $V_{DS} = 50\text{ V}$

Fig 8. Power gain as a function of output power; typical values



$I_{DQ} = 100\text{ mA}$ ;  $f = 225\text{ MHz}$ .

- (1)  $V_{DS} = 25\text{ V}$
- (2)  $V_{DS} = 30\text{ V}$
- (3)  $V_{DS} = 35\text{ V}$
- (4)  $V_{DS} = 40\text{ V}$
- (5)  $V_{DS} = 45\text{ V}$
- (6)  $V_{DS} = 50\text{ V}$

Fig 9. Drain efficiency as a function of output power; typical values



8. Package outline

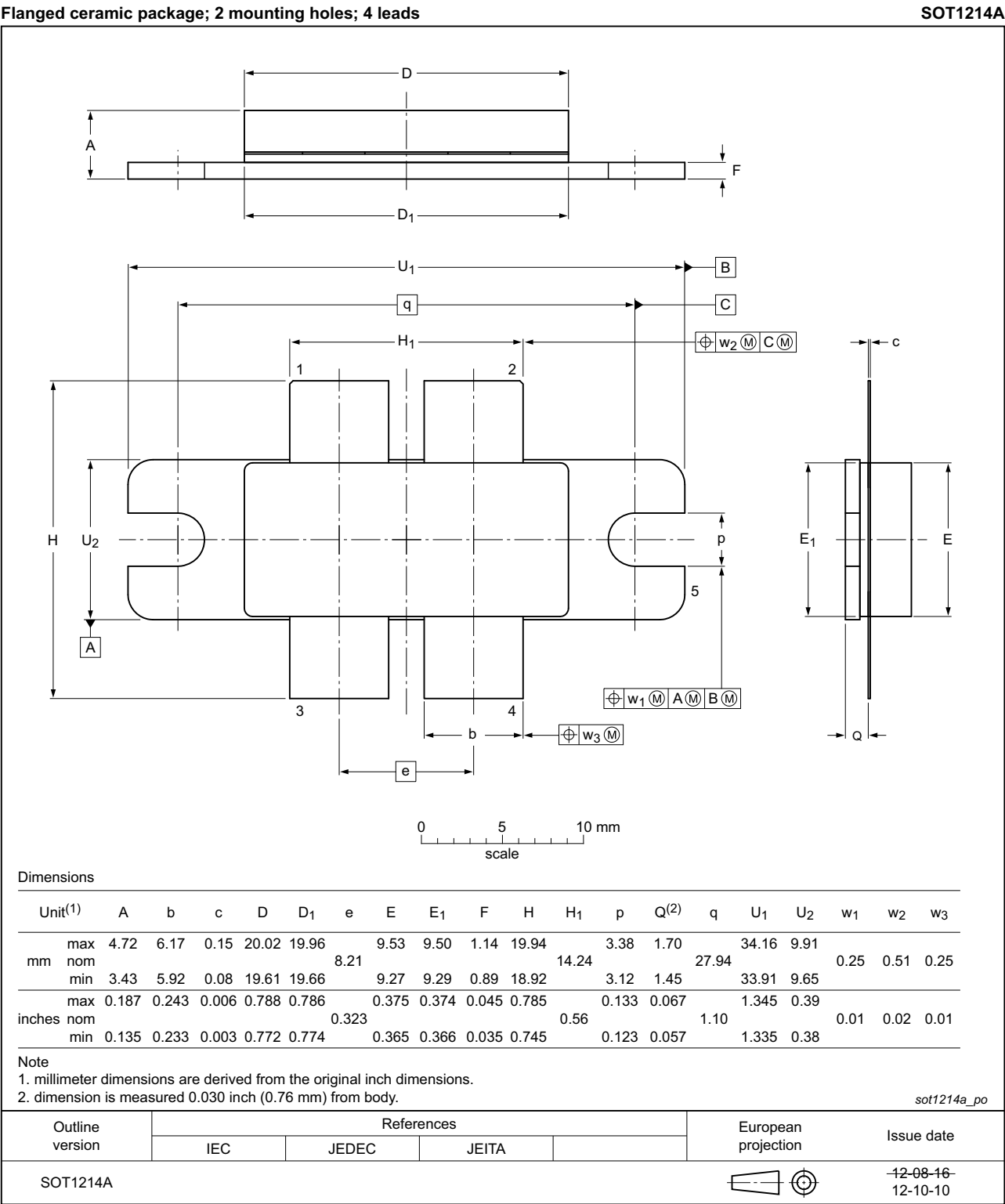


Fig 10. Package outline SOT1214A

Earless flanged ceramic package; 4 leads

SOT1214B

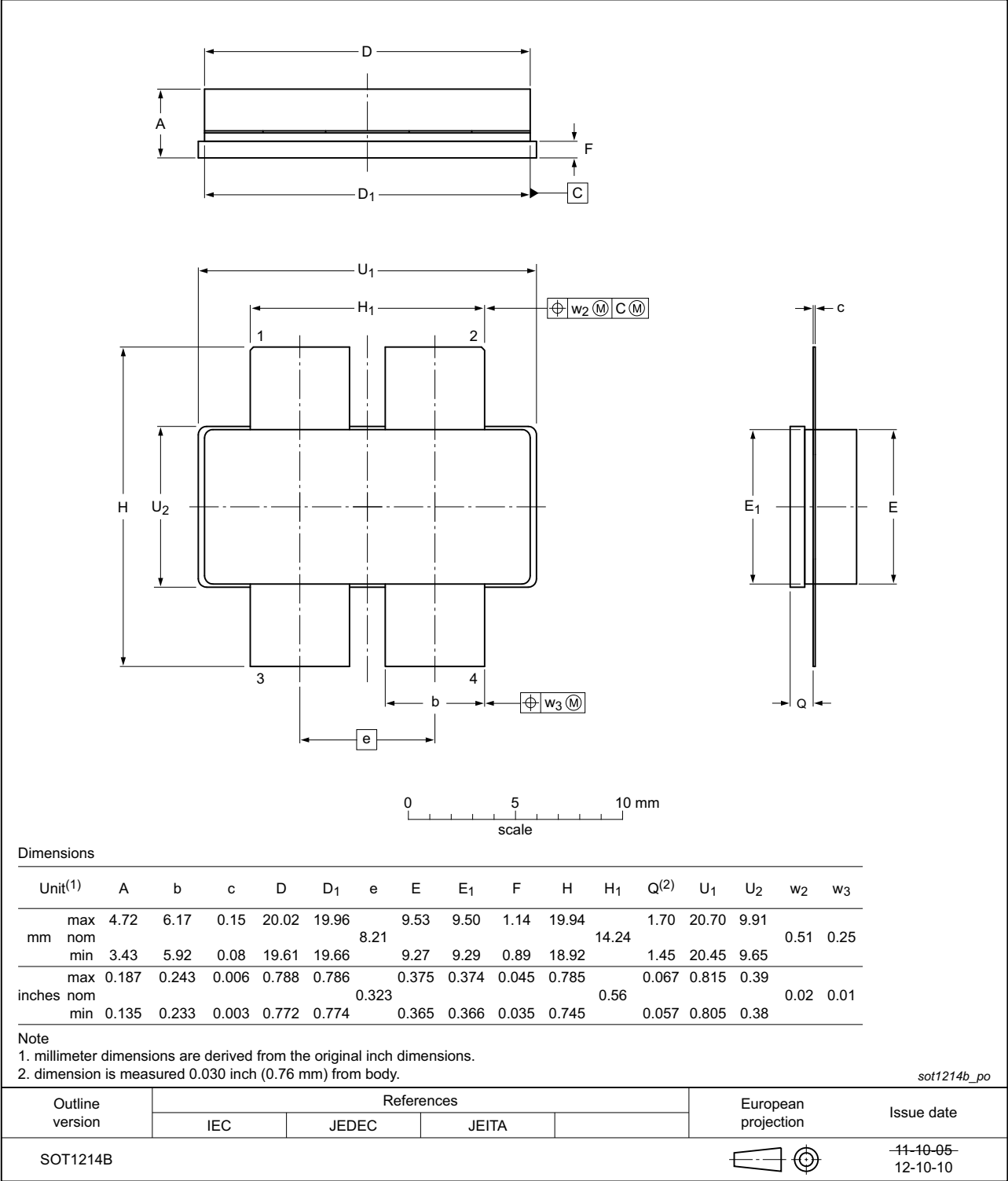


Fig 11. Package outline SOT1214B

## 9. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

## 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
XR	eXtremely Rugged

## 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF574XR_BLF574XRS v.1	20130620	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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